- Jan



PATENT Customer No. 22,852 Attorney Docket No. 04329.3260

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:		
Yoshio Ozawa		) )
Application No.: 10/791,870		Group Art Unit: 2818
Filed: I	March 4, 2004	) Examiner: HO, Tu Tu V.
1	NONVOLATILE SEMICONDUCTOR MEMORY CELL AND METHOD OF MANUFACTURING THE SAME	Confirmation No. 5239 )

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

## RESPONSE TO RESTRICTION REQUIREMENT

In a restriction requirement mailed May 6, 2005, the period for response extending through June 6, 2005, the Examiner required restriction under 35 U.S.C. § 121 between Group I, claims 1-11 and 20, characterized by the Examiner as drawn to a nonvolatile semiconductor memory cell and a memory card comprising the memory cell; and Group II, claims 12-19, characterized by the Examiner as drawn to a method of making a nonvolatile semiconductor memory cell. Applicant elects to prosecute Group I, claims 1-11 and 20 without traverse.

Please grant any extensions of time required to enter this response and charge any additional required fees to our deposit account 06-0916.

Respectfully submitted,

FINNEGAN, HENDERSON, FARABOW,

GARRETT & DUNNER, L.L.P.

Richard V. Burgujian

Reg. No. 31,744

Dated: June 6, 2005